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# **Surface Properties of Laser-Treated Molybdenum Disulfide Nanosheets for Optoelectronic Applications**

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#### Abstract

Transition metal dichalcogenide two-dimensional materials have attracted significant attention due to their unique optical, mechanical, and electronic properties. For example, molybdenum disulfide (MoS<sub>2</sub>) exhibits a tunable band gap that strongly depends on the numbers of layers, which makes it an attractive material for optoelectronic applications. In addition, recent reports have shown that laser thinning can be used to engineer an MoS<sub>2</sub> monolayer with specific shapes and dimensions. Here, we study laser-thinned MoS<sub>2</sub> in both ambient and vacuum conditions via confocal  $\mu$ -Raman spectroscopy, imaging X-ray photoelectron spectroscopy (i-XPS), and atomic force microscopy (AFM). For low laser powers in ambient environments, there is insufficient energy to oxidize MoS<sub>2</sub>, which leads to etching and redeposition of amorphous MoS<sub>2</sub> on the nanosheet as confirmed by AFM. At high powers in ambient, the laser energy and oxygen environment enable both MoS<sub>2</sub> nanoparticle formation and nanosheet oxidation as revealed in AFM and i-XPS. At comparable laser power densities in vacuum, MoS<sub>2</sub> oxidation is suppressed and the particle density is reduced as compared to ambient. The extent of nanoparticle formation and nanosheet oxidation in each of these regimes is found to be dependent on the number of layers and laser treatment time. Our

ASSOCIATED CONTENT

**Supporting Information** 

The Supporting Information is available free of charge on the ACS Publications website at DOI: 10.1021/acsami.8b04717. Additional results from the Raman, i-XPS, and AFM measurements (PDF)

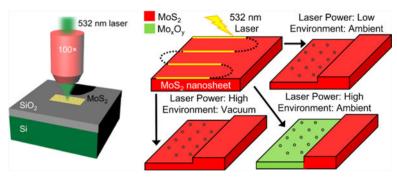
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results can shed some light on the underlying mechanism of which atomically thin MoS<sub>2</sub> nanosheets exhibit under high incident laser power for future optoelectronic applications.

#### **Graphical Abstract**



#### Keywords

molybdenum disulfide; X-ray photoelectron spectroscopy; confocal Raman spectroscopy; atomic force microscopy; nanoparticles; laser irradiation

#### INTRODUCTION

Two-dimensional materials such as graphene and transition metal dichalcogenides (TMDCs) have been extensively studied in the past few years due to their exceptional mechanical, electrical, and optical properties. <sup>1–3</sup> In some applications, TMDCs are preferred over graphene, given that graphene lacks a band gap. Moreover, TMDCs such as molybdenum disulfide (MoS<sub>2</sub>) exhibit a tunable band gap, which depends on the number of layers. <sup>4</sup> Due to weak van der Waals forces between the layers, it is possible to mechanically exfoliate layered TMDCs from their bulk form. <sup>4,5</sup> The resulting atomically thin MoS<sub>2</sub> nanosheets have demonstrated extraordinary electronic, photonic, and thermoelectric properties, which makes layered MoS<sub>2</sub> a strong candidate for various electronic and optoelectronic applications. <sup>6–9</sup>

As a result, several groups have been developing different methods by which to engineer and control the number of layers of  $MoS_2$ .<sup>10–14</sup> Most notably, Liu et al. demonstrated layer-by-layer thinning using argon plasma.<sup>15</sup> Their data show a reliable thinning of layered  $MoS_2$  down to a monolayer. Gomez et al. showed laser thinning of the  $MoS_2$  layers that had been mechanically exfoliated from a macroscopic  $MoS_2$  crystal. The authors confirmed the formation of monolayers with a desired shape, an attractive method to engineer  $MoS_2$  nanosheets.<sup>16</sup> However, their Raman results suggest that no oxidized  $MoS_2$  peaks were observed, which led them to conclude that no oxide layers were formed after laser thinning.

Most recently, Lee et al. measured the photoluminescence (PL) modulation of laser-treated monolayer  $MoS_2$ . <sup>17</sup> In that study, the authors established the three stages of photooxidation associated with laser irradiation periods in ambient conditions. The measurements showed a large PL modulation in the first step of oxidation, followed by a PL decrease and quenching.

The trends were associated with structural damage and oxygen adsorption on the  $MoS_2$  surface. However, the mechanism and implications behind the physical transformations of  $MoS_2$  nanosheets by laser treatment were still unclear. Moreover, recent work on  $MoS_2$  nanosheets have shown anomalous particles forming on the surface of the layered material after laser irradiation. Their characterization results showed that the particle density depends on the laser irradiation power, the laser irradiation time, and the number of layers. Still, the origin of these anomalous nanoparticles is unclear.

Here, we study laser-thinned MoS<sub>2</sub> in both ambient and vacuum conditions via confocal  $\mu$ -Raman spectroscopy, imaging X-ray photoelectron spectroscopy (i-XPS), and atomic force microscopy (AFM). For low laser powers in ambient conditions, it is shown that there is insufficient energy to oxidize the MoS<sub>2</sub> surface, but sufficient energy to etch and redeposit anomalous MoS<sub>2</sub> nanoparticles. In contrast, at high powers in ambient conditions, the laser energy and oxygen environment facilitate MoS<sub>2</sub> nanoparticle formation and nanosheet oxidation. Finally, at comparable power densities in vacuum, MoS<sub>2</sub> oxidation is suppressed, and the nanoparticle density is reduced relative to ambient experiments. Thus, we deduce that the formation of the anomalous MoS<sub>2</sub> nanoparticles is not limited to a specific environment, whereas MoS<sub>2</sub> oxidation is only possible in an oxygen environment (e.g., ambient conditions). Furthermore, the anomalous Raman trends are explained in terms of the observed physical changes to the MoS<sub>2</sub> surface, and attributed to changes in electronphonon coupling for monolayers and electron-photon coupling for multilayers. Overall, the unique combination of techniques sheds light on the physicochemical reasons for the observed properties of MoS<sub>2</sub> nanosheets after laser irradiation, which has significant implications for future TMDC-based applications.

#### **RESULTS**

#### Raman Characteristics of Laser-Thinned MoS<sub>2</sub> Nano-sheets.

Figure 1a shows the setup for the laser thinning process. This laser thinning technique enabled us to engineer monolayer  $MoS_2$  with the desired size and shape. The optical images of the targeted  $MoS_2$  nanosheet before and after laser thinning are shown in Figure 1b,c, respectively. The initial thickness of the flake is estimated to be >5L based on the difference between the  $A_{1g}$  and  $E_{2g}$  Raman peak positions (Figures 1d and S1b–e).<sup>19</sup> After laser thinning, the nanosheet reveals characteristics of a bilayer (2L), as evident by the shifts in the  $A_{1g}$  and  $E_{2g}$  peaks in Figure S1b. All the Raman measurements were collected after laser thinning. In Figure S1a, we show the Raman measurements at different incident energy densities (energy per unit area) using a 532 nm laser on a 130 nm thick nanosheet. In this figure, the highlighted parts show the number of layers based on the difference in the Raman

peaks for 
$$A_{1g}$$
 and  $E_{2g} \left( \Delta \omega = \omega_{A_{1g}} - \omega_{E_{2g}} \right)$ , as previously reported.<sup>19</sup> The estimated etching

rate is shown in the inset of the figure and varies with the number of layers etched. This variability in the etching rate with increased number of layers is likely due to strong interlayer coupling between MoS<sub>2</sub> layers.

To evaluate the formation of oxide on the  $MoS_2$  surface, we also spatially mapped the Raman intensities at 289 and 820 cm<sup>-1</sup>, both of which have been associated with  $MoO_3$ . At these two peak positions, there is no observable Raman signal in the maps (Figure 1e) or spectra (Figure S1), which could imply that (1) an oxide layer did not form or (2) the oxide layer is not in the form of  $MoO_3$ .

## i-XPS Measurements of Native and Laser-Treated MoS<sub>2</sub> Nanosheets Under Different Environmental Conditions.

i-XPS was performed on native and laser-treated MoS<sub>2</sub> flakes. Figure 2 shows the results from the processed i-XPS measurements on native and laser-treated MoS<sub>2</sub> nano-sheets in ambient conditions, as shown in the optical images in Figure 2a. Ambient, in this study, is synonymous with an air environment. Analysis of the images around the S 2s region at  $\approx$ 227 eV reveals that the native flakes retained sulfur content (Figure 2b), suggesting that their surface composition is still consistent with MoS<sub>2</sub>. Additionally, images associated with the Mo 3d<sup>5</sup> peak maximum near 229.8 eV, attributed to MoS<sub>2</sub>, further corroborates this result (as shown in Figure S2a). In contrast, there is no significantly increased signal intensity observed in the region treated with 8.3 mW (high) laser power attributed to sulfide or MoS<sub>2</sub>. However, there is evidence of an Mo 3d signal at around 235 eV, attributed to the 3d<sup>3</sup> peak associated with oxidized MoS<sub>2</sub> (Mo<sub>X</sub>O<sub>y</sub>), which is only present at the treated flake (Figure 2c). To extract spectra from the raw unprocessed images, masks were created from the S<sub>sulfide</sub>, Mo<sub>ox</sub>, and SiO<sub>2</sub> images to identify regions of interest (ROI) with minimal overlap attributed to the native and laser-treated MoS<sub>2</sub> flakes, as well as the substrate (Figure 2d).

Spectra for Mo 3d, S 2s, and O 1s regions associated with pixels from each mask are provided in Figure 2e, whereas the Si 2p region, used principally for energy correction, is provided in the Supporting Information (SI) (Figure S3). Indeed, Mo 3d<sup>5</sup> and S 2s spectra (left) for the native, untreated flakes exhibit peak maxima at 229.8 eV and 227.0 eV, respectively, consistent with literature values for the photoelectric transitions for MoS<sub>2</sub>, in a ratio of 1.9:1 after correcting for the sensitivity factors that relate to the different cross sections for photoemission.<sup>21</sup> In contrast, sulfur is undetectable in the laser-treated MoS flakes, with only slight increases in signal intensity attributed to the satellite peaks for the shifted Mo<sub>ox</sub> 3d<sup>3</sup> peak, suggesting that the sulfide characteristics are completely removed. Indeed, the molybdenum spectra shift in peak maximum by roughly 2 eV to 231.8 eV for the Mo<sub>ox</sub> 3d<sup>5</sup> feature. Notably, the spectral features broaden in full width at half-maximum (FWHM), suggestive of a distribution of oxide (IV–VI) species within the spectral envelope. However, because MoO<sub>2</sub> is found at the binding energies proximate to MoS<sub>2</sub> and MoO<sub>3</sub> is typically found at positions 0.5–1.0 eV higher in binding energy, we suspect there is a significant contribution from an intermediary oxide component, such as Mo<sub>2</sub>O<sub>5</sub>, which has been demonstrated to be present near the observed fitted peak position.<sup>22–24</sup>

Consistent with the observed transformations in the Mo and S spectra, the O 1s window also transforms from one Gaussian-like feature to two features when comparing native and treated spectra, respectively. This reflects the difference between oxygen attributed to the  ${\rm SiO_2}$  ( ${\rm O_{Si}}$ ) and the oxidized molybdenum ( ${\rm O_{Mo}}$ ) at peak positions of 532.9 eV and 531.0 eV, respectively. The  ${\rm O_{Mo}/Mo_{ox}}$  value is approximately 2.1:1, suggesting either the existence of

oxygen vacancies or that the fit of the spectra is imperfect. Table S1 provides additional detail on the relative atomic percentages associated with the fitted spectra extracted from ROIs in the composite map for native and laser-treated  $MoS_2$  flakes (fitted spectra available in Figure S4). Although these values are only estimates and accordingly lack uncertainty due to factors explained in the SI and Methods section, we thought it important to demonstrate the degree of agreement between experimentally derived values and theoretical values. It is also important to note two points regarding the formation of a  $Mo_{ox}$  layer: (1) the result regarding  $MoS_2$  oxidation has been replicated in another measurement, demonstrating the repeatability of the finding (see Figure S5) and (2) the dominant signs of Mo oxidation are not observed when the laser thinning is performed at lower powers such as 0.93 mW (data not shown).

Figure 3 shows the results from i-XPS measurements on native  $MoS_2$  flakes and  $MoS_2$  flakes laser-treated with 7.2 mW (high laser power) in vacuum conditions. The imaged region contains both native and laser-treated  $MoS_2$  flakes, with the laser-treated flake near the middle of the analysis area (Figure 3a). As shown in Figure 3b, the images reveal a significant sulfur contribution remained, as evident from the well-defined  $S_{sulfide}$  region (see Figure S2b,d for  $MoS_2$  and Si 2p for the processed images). The  $Mo_{ox}$  image was devoid of any large localized contributions at the 235.0 eV peak position (Figure 3c). Together, these observations suggest that the surface was substantially less photochemically transformed than in the previous ambient experiments. Because the composite map lacks a well-defined ROI for  $Mo_{ox}$ , a manually selected ROI (green rectangle) was made in addition to the  $SiO_2$  mask and the  $S_{sulfide}$  mask (Figure 3d).

Analysis of the spectra reveal only minimal differences between the spectra from the sulfide mask and the spectra from the manually selected laser-treated area (Figures 3e and S3b for Si 2p). Indeed, this suggests that in the presence of vacuum, the laser-treated sections remain  $MoS_2$ . Both the native and laser-treated  $MoS_2$  spectra reveal a S/ $Mo_{sulfide}$  relative sensitivity factor-adjusted intensity of roughly 1.8 under vacuum conditions (Table S1). Based on the fitting, a small amount of  $Mo_xO_y$  may be present in the treated section; however, it is impossible to differentiate this from the noise with any reasonable certainty.

#### AFM and Raman Measurements of Laser-Treated MoS<sub>2</sub> Nanosheets.

Figure S6 shows the morphology of a laser-thinned MoS<sub>2</sub> nanosheet. The optical image of the targeted nanosheet is highlighted in the image of Figure S6a. The power and time used for laser thinning is analogous to the reported values above in an ambient environment. The AFM results in Figure S6 show a clear transition from multilayer MoS<sub>2</sub> to monolayer MoS<sub>2</sub>, confirming our Raman results obtained before and after thinning. The AFM results can be interpreted by examining Figure S6b–d, which cover three major regions: native, at the edge of the native and thinned regions, and postlaser thinning region, respectively. These regions are highlighted in the AFM image of Figure S6a. In Figure S6c, a clear transition from multilayer to monolayer is observed. Moreover, it is found that the roughness of the nanosheet significantly increased after thinning, as shown in Figure S6d.

Figure 4 illustrates the morphology of laser-treated monolayers, three layers (3L), and five layers (5L) of  $MoS_2$  nanosheets. In this figure, laser treatments are targeted at specific spots

on the surface of the  $MoS_2$  nanosheet using a 532 nm laser with varying optical powers and treatment times, as labeled in Figure 4a–c. For all layers, the AFM results show an instant thinning for laser powers of 4.7 and 8.3 mW regardless of the treatment time. However, for 0.93 mW, we see the formation of anomalous particles around the treatment sites. In fact, we observe nanoparticles forming around all the treatment points. These nanoparticles have been reported previously and their volume has been shown to depend on the number of layers and the treatment conditions. <sup>18</sup> In Figure S14, we show the SEM images of some laser-treated  $MoS_2$  sites. Our results show consistency in the nanoparticle formation with laser power and treatment time, supporting the previous report.

The Raman characteristics measured after treating MoS<sub>2</sub> nanosheets are shown in Figure 5ac for 1L, 3L, and 5L, respectively. Raman measurements are collected after laser treatments. In these figures, we plot the Raman characteristics versus the treatment time for 0.93 mW laser power. We notice that for 3L and 5L, the intensity of the  $A_{1g}$  and  $E_{2g}$  peaks drop equally, whereas the FWHM of each peak increases slightly. The Raman shift for both peaks does not show any shift. However, the monolayers exhibit a different behavior, as shown in Figure 5a. The Raman shift for the A<sub>1g</sub> peak shows a slight upshift, which is also observed on different samples as in Figure S7, whereas the Raman shift for the  $E_{\mathrm{2g}}$  peak does not show noticeable shift within the measurements sensitivity. Moreover, the intensity of the  $A_{1g}$ peak exhibits a different behavior than the  $E_{2g}$  peak. In fact, the  $E_{2g}$  peak shows a significant decrease in intensity as compared to the A<sub>1g</sub> peak. Other 1L samples show similar effects. The linewidth (FWHM) for the A<sub>1g</sub> peak decreases with increasing treatment time, whereas the  $E_{2g}$  linewidth is constant. This anomalous behavior has been observed previously in laser-irradiated MoS<sub>2</sub> and was attributed to p-doping of the monolayer. <sup>17</sup> However, this explanation does not take into consideration the effect of the photoinduced nanoparticles on the measured Raman characteristics. This point will be addressed in the Discussion section.

To better understand the anomalous nanoparticles, the surface morphology and the Raman characteristics of laser-treated  $MoS_2$  were measured at similar energy densities in vacuum. Figures 6 and 7 show the laser-treated monolayer and four layer (4L)  $MoS_2$  nanosheets in vacuum, respectively. Remarkably, we are able to produce these nanoparticles with similar power density and at different treatment times. The density of the nanoparticles increases with treatment time. Figures 6e and 7e show the Raman spectra before and after treatments for 1L and 4L  $MoS_2$ , respectively. The Raman shift of the  $A_{1g}$  peak for 1L postlaser treatment is downshifted and broadened, indicative of heating. However, for the 4L nanosheet, despite the existence of photoinduced nanoparticles on the surface of the  $MoS_2$ , the Raman characteristics lack any noticeable change with treatment time, which can be attributed to a strong interlayer coupling.

In Figures S7–S9, the Raman characteristics and topography after laser-treating additional  $1L \, MoS_2$  in different environments are shown. The Raman characteristics of laser-treated  $MoS_2$  in ambient and vacuum are shown in Figures S7 and S8, respectively. We observe similar behavior as the results demonstrated in Figures 6 and 7. The Raman shift for the  $A_{1g}$  mode downshifts and broadens in the vacuum environment with increasing treatment times, whereas the mode upshifts and becomes narrower (reduced linewidth) after laser treatments in ambient. The opposing behavior in ambient and vacuum can be attributed to the formation

of photoinduced nanoparticles as discussed below. Based on the AFM before and after treatments in Figure S9, we deduce that the formation of the nanoparticles is not restricted to a specific environment. Nonetheless, we see a decrease in particle density for laser-treated  $MoS_2$  in vacuum compared to air. The reason behind this change in the particle density is still unclear. However, we suspect that the significant reduction in oxygen in the chamber can affect the physioadsorption mechanism, leading to reduced particle density.

#### DISCUSSION

Figure 8 illustrates a proposed mechanism when a laser with certain power is incident on an MoS<sub>2</sub> nanosheet. For low laser power and in an ambient environment, there is not enough energy to oxidize MoS<sub>2</sub>, which leads to etching and possibly redeposition of amorphous MoS<sub>2</sub> on the surface of the nanosheet. In contrast, at high powers in ambient conditions, the laser energy and oxygen environment enable both MoS<sub>2</sub> nanoparticle formation and nanosheet oxidation. However, when this high laser power is incident on an MoS<sub>2</sub> nanosheet in vacuum, no oxidation occurs due to the lack of oxygen. Hence, only etching redeposition of amorphous MoS<sub>2</sub> nanoparticles on the surface occurs. Accordingly, based on this mechanism, two major factors are necessary for MoS<sub>2</sub> oxidation: high laser power and oxygen; however, relatively low laser power (0.93 mW) for at least 60 s, regardless of the environment, can induce nanoparticles on the surface of the nanosheet.

The anomalous Raman intensity behavior for  $A_{1g}$  and  $E_{2g}$  of laser-treated monolayers can be explained by considering the various terms that affect the Raman intensity characteristics. The Raman intensity is sensitive to the electron–photon coupling, the electron–phonon coupling, and the resonance condition. Accordingly<sup>25–27</sup>

$$I \propto \left| \sum_{a} \frac{M^{d}(\mathbf{k} - \mathbf{q}, jb)M^{ep}(\mathbf{q}, ba)M^{d}(\mathbf{k}, aj)}{\Delta E_{aj} \left( \Delta E_{aj} - \hbar \omega \right)} \right|^{2}$$

where  $M^d$  and  $M^{ep}$  are the electron–photon coupling matrix element and the electron–phonon coupling matrix element, respectively.  $E_{aj} = E_L - (E_a - E_j) - i\gamma$ , where  $E_L$  is the excitation laser energy and  $\gamma$  is the resonance broadening factor. The subscripts j, a, and b are the initial state, final state, and scattered state, respectively. The possibility of a change in the resonance condition can be eliminated because there is no change in the optical transition and no external forces that could induce any substantial strain on the nanosheet. We now consider the effect of electron–photon coupling,  $M^d$ , on the intensity of the Raman spectra. Changes in  $M^d$  would induce changes in the photoluminescence intensity. However, we do not see any noticeable change in the intensity of the PL before and after treatments (Figure S10a). Moreover, changes in  $M^d$  should produce the same changes in the Raman spectra for all the Raman modes. In our measurements, each of the  $A_{1g}$  and  $E_{2g}$  show different profiles, which supports the claim that  $M^d$  is not the cause of this observed intensity profile. This leaves the electron–phonon coupling  $M^{ep}$ , which is expected to show different intensity profiles for each of the  $A_{1g}$  and  $E_{2g}$ . Various groups have calculated  $M^{ep}$  and showed they differ for each  $A_{1g}$  and  $E_{2g}$ . Consequently, we believe that the formation

of these nanoparticles on  $MoS_2$  monolayers contributes to affecting the electron–phonon coupling of the  $A_{1g}$  and  $E_{2g}$  modes, resulting in two distinct Raman intensity profiles.

The anomalous behavior for the linewidth of  $A_{1g}$  and  $E_{2g}$  as a function of treatment time can be explained by considering the treatment time for 0.93 mW. Taube et al. have investigated the thermal properties of monolayer  $MoS_2$ . They observed a nonlinear phonon behavior for  $A_{1g}$  and  $E_{2g}$  for a wide temperature range. In their measurements, the linewidth of  $A_{1g}$  increases with increasing temperature, whereas  $E_{2g}$  is invariant. These results are consistent with our results, which show a change in the linewidth of the  $A_{1g}$  mode only, whereas  $E_{2g}$  is constant. As a result, we believe that the formation of the  $MoS_2$  nanoparticles adds an additional phonon decay path in the cross plane  $A_{1g}$  mode. This phonon decay path is consistent with the decrease in the linewidth of  $A_{1g}$  peak because  $A_{1g}$  phonon lifetime is proportional to the linewidth. Moreover, the formed nanoparticles affect the intensities of the  $A_{1g}$  and  $E_{2g}$  modes. It is important to note that the Raman mode intensity is proportional to the electron–phonon interaction. Although the linewidth of the  $E_{2g}$  mode is invariant, the intensity of the mode is affected by the formation of the nanoparticles, which readily affects the electron–phonon interaction.

The downshift of the  $A_{1g}$  mode in vacuum after treatment illustrated in Figure 6 can be due to the lower photoinduced particle density in vacuum compared to ambient treatments. In Figures S11 and S12, the surface roughness of the vacuum-treated spots is smaller than that for ambient-treated spots. We also observe more nanoparticles around the ambient spots. Although previous reports show that oxygen doping can cause an upshift in  $A_{1g}$  after ambient treatments,  $^{30}$  it is important to note that we do not observe changes in the PL profile before and after treatments in ambient, as shown in Figure S10a. Hence, in a vacuum environment, the nanoparticle density is not sufficient enough to create a phonon decay path and induce the  $A_{1g}$  phonon upshift observed after ambient treatments with similar treatment conditions.

Contrary to monolayers, multilayers (>3L) have been shown to exhibit a different behavior. Both the  $A_{1g}$  and  $E_{2g}$  intensities decrease equally, with a slight increase in the linewidth of each peak. In fact, we see a noticeable decrease in the PL intensity at the treated sites, as shown in Figure S10b. The photo-luminescence is proportional to the photoemission and the photoabsorption processes, which are strong functions of the electron–photon coupling. Small changes in the electron–photon coupling will significantly affect the PL intensity. Thus, the effects observed in multilayer  $MoS_2$  are attributed to changes in the electron–photon coupling  $M^d$ , as evident by the overall effects on all Raman mode intensities along with the photoemission intensity.

#### **CONCLUSIONS**

In conclusion, we have investigated the influence of the environment on laser-treated  $MoS_2$  nanosheets. In ambient conditions, etching and redeposition of amorphous  $MoS_2$  on the nanosheet is found to occur at low laser powers, and  $MoS_2$  nanoparticle formation and nanosheet oxidation are found to transpire at high laser powers; both of which are shown in the AFM and i-XPS results, respectively. Interestingly, the Raman results show no

observable signal at the two peak positions related to  $MoO_3$ , despite the clear evidence for an oxide layer in the i-XPS. This suggests that the oxidation process results in something other than  $MoO_3$ , such as  $Mo_xO_y$ , where the molybdenum is in an intermediate state between Mo(VI) and Mo(IV). It is also shown that the Raman trends are significantly different for monolayers and multilayers; the disparities are explained by considering the various terms that affect the Raman characteristics. In more detail, the intensity changes observed for  $A_{1g}$  and  $E_{2g}$  peaks for monolayers are attributed to changes in the electron–phonon coupling, whereas the observed intensity trends for  $A_{1g}$  and  $E_{2g}$  peaks for multilayers are due to changes in the electron–photon coupling. In vacuum conditions,  $MoS_2$  oxidation is suppressed, and the particle density is reduced as compared to ambient conditions. Moreover, Raman spectra before and after treatments in vacuum downshift and broaden for monolayers, suggestive of heating, but remain unchanged for multilayers, which is attributed to a strong interlayer coupling. In all, the results presented here shed light on the effects of environment and laser conditions on  $MoS_2$  nanosheets, which has great implications on future  $MoS_2$ -based photodetector applications.

#### **MATERIALS AND METHODS**

#### Sample Preparation.

MoS $_2$  nanosheets (2H semiconducting phase) were prepared using micromechanical exfoliation with scotch tape. The samples were exfoliated on top of an SiO $_2$ /Si substrate, with an SiO $_2$  thickness of 300 nm. Confocal Raman measurements were used to determine the thickness of MoS $_2$  flakes. <sup>19</sup> Nanosheets that exhibit <5L were chosen for further experimental work. For the laser treatments, the power varied from 0.93 mW (low power) to 8.3 mW (high power) and the treatment times varied from 0.01 s to 3 min. Laser treatments with the 532 nm laser were administered in two configurations: (1) in ambient conditions with a  $100\times$  lens to quantify the laser conditions for MoS $_2$  nanoparticle formation and layer oxidation and (2) in ambient and vacuum conditions in a chamber with a glass-compensated long-working distance  $40\times$  lens to identify the influence of environment at similar energy densities. To compensate for the power loss caused by the optical window in the vacuum chamber, and using the exposure time as a variable, we delivered the same amount of energy density to the MoS $_2$  surface. For Raman and AFM, the laser-spot spacing was large enough ( $\approx 3~\mu m$ ) to minimize interactions with subsequent spots, whereas for i-XPS, the laser-spot spacing was small enough ( $\approx 100$  nm) to ensure complete coverage of the selected nanosheet.

#### Raman Measurements.

Confocal  $\mu$ -Raman spectroscopy (Renishaw) was used to measure the Raman and PL characteristics of the treated nanosheets. The Raman and PL maps were obtained using an automated stage. The Raman peaks were readily measured before and after treatments to ensure consistency. A custom-made sealed stage was used in vacuum experiments, with vacuum levels as low as 20 mTorr. For the vacuum setup, we used a lower-magnification objective lens for laser treatments and Raman measurements, but kept the delivered energy density similar.

#### i-XPS Measurements.

Laser-treated MoS<sub>2</sub> nanosheets were located by a light microscope from Leica Microsystems (Buffalo Grove, IL) before i-XPS. The i-XPS measurements were carried out on an Axis Ultra DLD Imaging X-ray Photoelectron Spectrometer from Kratos Analytical (Chestnut Ridge, NY) under ultrahigh vacuum conditions ( $P_{base} = 2 \times 10^{-9}$  Torr). After locating the MoS<sub>2</sub> nanosheet, the i-XPS was performed using Mg Ka X-rays operating at 300 W (20 mA, 15 kV) to achieve photoemission with charge neutralization. The original imaged area, defined in the instrument as a field of view three (FOV3), for images taken in high-resolution mode, was determined to be 178  $\mu$ m × 178  $\mu$ m using an in-house spatial calibration tool. i-XPS acquired images at the pass energy 40 eV for the Mo 3d/S 2s (219–240.2 eV), the Si 2p (95.2–104.8 eV), and the O 1s (523.2–534 eV) regions at the step sizes of 0.4 eV/image across said ranges and for 900 s/image, 420 s/image, and 300 s/image, respectively, for a total of 107 images.

Acquired images were processed initially to correct for stage drift and shifting in the analysis position due to the energy-dependent response of photoelectrons to magnetic fields using a modified version of a Mathematica (Wolfram, Champaign, IL) script provided in commented form in the SI (Figure S13).<sup>32</sup> Subsequently, the entire data set was processed in CasaXPS using a modified procedure, which had been previously published to remove outliers and noise, process spectra from each pixel to recreate chemically specific images, and generate smoothed masks reflecting ROIs specific to MoS<sub>2</sub>, MoO<sub>3</sub>, and SiO<sub>2</sub>.<sup>24</sup> To accomplish this, the spectral features for S<sub>sulfide</sub> 2s, Mo<sub>ox</sub> 3d<sup>3</sup>, and Si 2p were chosen to recreate these processed images because they provided the least degree of signal overlap for the unmodified MoS<sub>2</sub>, photochemically transformed Mo<sub>x</sub>O<sub>y</sub>, and SiO<sub>2</sub> substrate, respectively. These processed images were converted into masks based on the intensity and then applied to the raw image stacks to extract and form spectra for the O 1s, Mo 3d, S 2s, and Si 2p regions. The spectra were energy corrected by shifting the fitted Si 2p peak maximum to 103.6 eV, consistent with the average value of 29 references for SiO<sub>2</sub>. <sup>24,33</sup> Subsequently, the remaining spectra were fit with Gaussian peaks and adjusted using elemental relative sensitivity factors of 3.585, 0.391, 0.371, and 0.736 for Mo, S, Si, and O, respectively. Element related concentrations should be considered estimates due to several factors including, but not limited to, unknown errors associated with drift correction, whereas detector background was not flat-field corrected, chemical state information attributed to poor energy resolution spectra, and SiO<sub>2</sub> electron attenuation through MoS<sub>2</sub> layers may attenuate resulting in suboptimal rsf assignment. Each measurement reflects only one measurement.

#### **AFM Measurements.**

Intermittent-contact mode AFM was performed on both MFP-3D AFM (Asylum Research, Santa Barbara, CA) and Cypher S AFM (Asylum Research, Santa Barbara, CA) to measure the surface topographies of the treated MoS<sub>2</sub> nanosheets. Two different AFM probes were used: (1) AC240 cantilevers (Olympus) with a nominal normal spring constant of 2 N/m and a nominal resonance frequency of 70 kHz and (2) PPP-FMR cantilevers (Nanosensors) with a nominal normal spring constant of 2 N/m and a nominal resonance frequency of 75 kHz.

The lateral scan rates varied from 0.6 to 1.0 Hz and the number of pixels was constant at 512  $\times$  512.

#### Supplementary Material

Refer to Web version on PubMed Central for supplementary material.

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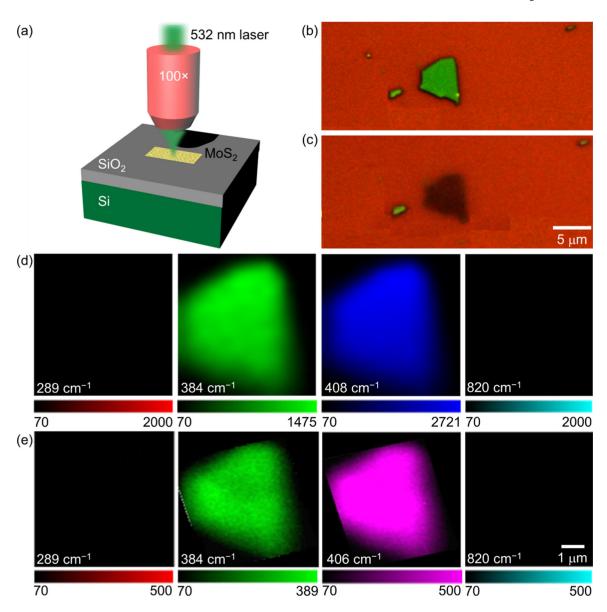


Figure 1. Exfoliated  $MoS_2$  nanosheets. (a) Schematic illustration of the Raman setup used to treat and measure  $MoS_2$  nanosheets. Optical images taken (b) before and (c) after laser thinning of the  $MoS_2$  nanosheet. Raman intensity maps of  $MoS_2$  and  $MoO_3$  vibrational peaks (d) before and (e) after laser thinning of the  $MoS_2$  nanosheet.

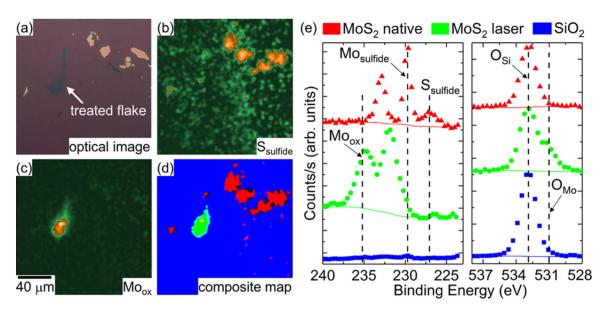


Figure 2. i-XPS measurements on native and laser-treated  $MoS_2$  nanosheets treated in ambient conditions. (a) Optical image of the area containing native and laser-treated nanosheets. (b) Processed image attributed to  $S_{sulfide}$  2s signal. (c) Processed image attributed to  $Mo_{ox}$  3d<sup>3</sup> signal. (d) Composite map of masks associated with processed images of  $Mo_{ox}$  (green),  $S_{sulfide}$  (red), and  $SiO_2$  (blue) signals. Yellow, teal, and pink reflect an overlap in masks, whereas black reflects an absence in masks. (e) i-XPS spectra from the raw images based on pixels from the ROIs defined in the composite map. The Mo 3d and S 2s regions (left) and the O 1s region (right).

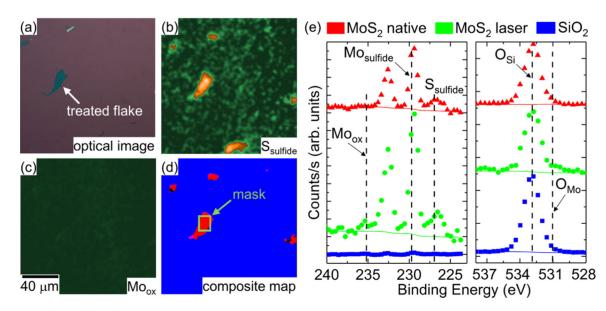


Figure 3. i-XPS measurements on native and laser-treated  $MoS_2$  nanosheets treated in vacuum. (a) Optical image of the area containing native and laser-treated nanosheets. (b) Processed image attributed to  $S_{sulfide}$  2s signal. (c) Processed image attributed to  $Mo_{ox}$  3d<sup>3</sup> signal. (d) Composite map of masks associated with processed images of  $Mo_{ox}$  (green),  $S_{sulfide}$  (red), and  $SiO_2$  (blue) signals. (e) i-XPS spectra from the raw images based on pixels from the ROIs defined in the composite map. The Mo 3d and S 2s regions (left) and the O 1s region (right).

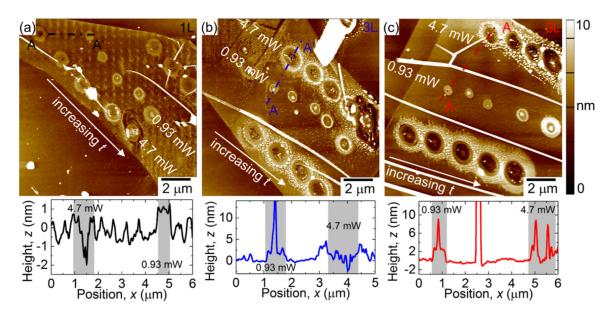


Figure 4. AFM images and cross sections of (a) one layer (1L), (b) 3L, and (c)  $5L MoS_2$  nanosheets laser-treated in ambient conditions.

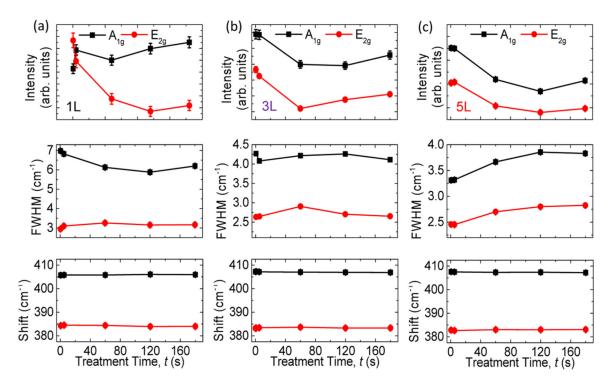


Figure 5. Raman intensity, linewidth (FWHM), and shift of (a) 1L, (b) 3L, and (c) 5L  $MoS_2$  nanosheets laser-treated in ambient conditions.

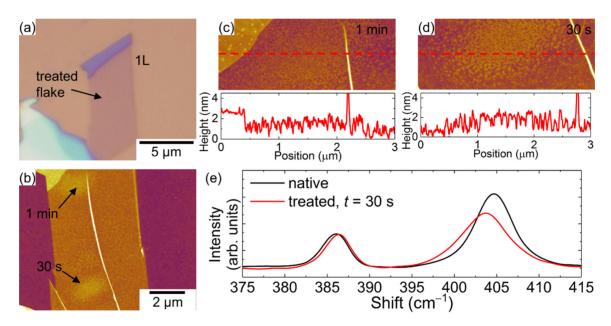


Figure 6. AFM images and Raman measurements on  $1L \, MoS_2$  nanosheets laser-treated in vacuum. (a) Optical image and (b) AFM image of laser-treated  $MoS_2$  nanosheet. Higher-magnification AFM images of each treatment locations for (c) 1 min and (d) 30 s laser treatments. (e) Raman spectra before and after the 30 s laser treatment.

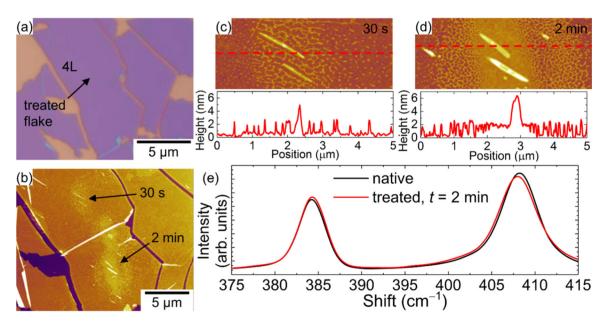


Figure 7. AFM images and Raman measurements on  $4L\ MoS_2$  nanosheets laser-treated in vacuum. (a) Optical image and (b) AFM image of laser-treated  $MoS_2$  nanosheet. Higher-magnification AFM images of each treatment locations for (c)  $30\ s$  and (d)  $2\ min$  laser treatments. (e) Raman spectra before and after the  $2\ min$  laser treatment.

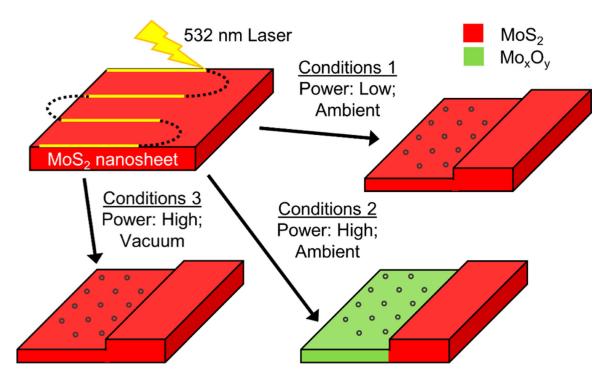


Figure 8.

Laser-induced thinning conditions mostly result in nanoparticle formation (blue circles) on a MoS<sub>2</sub> surface; however, different conditions impact surface chemistry. (1) Low-power laser and the presence of atmospheric oxygen retains the MoS<sub>2</sub> chemical structure. (2) High-power laser and the presence of atmospheric oxygen results in molybdenum oxidation. (3) High-power laser in the presence of vacuum also retains MoS<sub>2</sub> chemical structure.